

Domain and superdomain structures in ferroelectric PbTiO₃ based heterostructures

Ludovica Tovaglieri¹, Marios Hadjimichael^{1, 2}, Pau Torruella³, Chih-Ying Hsu^{1, 3},
Lukas Korosec¹, Duncan T.L. Alexander³, Patrycja Paruch¹, Jean-Marc Triscone¹,
Céline Lichtensteiger¹

¹*Department of Quantum Matter Physics, University of Geneva, 24 Quai Ernest-Ansermet,
1211 Geneva, Switzerland*

²*Department of Physics, University of Warwick, Coventry CV4 7AL, United Kingdom*

³*LSME, Ecole Polytechnique Fédérale de Lausanne (EPFL), CH-1015 Lausanne, Switzerland*

PbTiO₃ is a ferroelectric material that undergoes a bulk paraelectric-to-ferroelectric phase transition at a critical temperature (T_c) of 765 K, with a polarization that develops along the c-axis primarily driven by ionic displacements. Theoretical studies of domain structures in PbTiO₃ thin films reveal complex phase diagrams, with distinct domain configurations as a function of different parameters such as epitaxial strain, film thickness, electrostatic boundary conditions, and deposition temperature [1].

In prior work on PbTiO₃ heterostructures grown epitaxially on (110)_o-oriented DyScO₃ substrates with both top and bottom SrRuO₃ electrodes [2,3], we demonstrated an evolution in domain structure—from flux-closure configurations to an a/c-phase—as the film thickness increased. Beyond a critical PbTiO₃ thickness, these domains were observed to organize into larger-scale superdomain structures [2,3].

In the present study, we examine a series of heterostructures with PbTiO₃ layer thicknesses ranging from 18 to 720 unit cells, with a 22 nm-thick SrRuO₃ bottom electrode [4]. Using a combination of atomic force microscopy, vertical and lateral piezoresponse force microscopy, scanning transmission electron microscopy, and x-ray diffraction, we reconstruct the three-dimensional domain configurations and identify distinct superdomain types. Our analysis reveals that the superdomain periodicity scales with film thickness, and we observe the formation of superdomain walls. These walls exhibit potentially unique switching characteristics compared to conventional domain walls, suggesting a route toward enhanced functional properties in ferroelectric heterostructures.

References:

- [1] Schlom et al., Annu. Rev. Mater. Res., 37.1, 589-626 (2007)
- [2] Lichtensteiger et al., APL Mater. 11, 061126 (2023)
- [3] Lichtensteiger et al., APL Mater. 11, 101110 (2023)
- [4] Tovaglieri et al., APL Mater. 13, 021118 (2025)